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Title	Quasiparticle interference on the surface of Bi <sub>2</sub> Se <sub>3</sub> induced by cobalt adatom in the absence of ferromagnetic ordering
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Relation	

## Quasiparticle interference on the surface of $\text{Bi}_2\text{Se}_3$ induced by cobalt adatom in the absence of ferromagnetic ordering

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Quasiparticle interference induced by cobalt adatoms on the surface of the topological insulator  $\text{Bi}_2\text{Se}_3$  is studied by scanning tunneling microscopy, angle-resolved photoemission spectroscopy, and x-ray magnetic circular dichroism. It is found that Co atoms are selectively adsorbed on top of Se sites and act as strong scatterers at the surface, generating anisotropic standing waves. A long-range magnetic order is found to be absent, and the surface state Dirac cone remains gapless. The anisotropy of the standing wave is ascribed to the heavily warped iso-energy contour of unoccupied states, where the scattering is allowed due to a nonzero out-of-plane spin.

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### I. INTRODUCTION

Recently topological insulators (TIs),<sup>1-3</sup> with a nontrivial metallic surface state in the bulk energy gap induced by spin-orbit coupling have invoked much theoretical and experimental research. An odd number of surface states with a spin helical texture has been established for  $\text{Bi}_{1-x}\text{Sb}_x$ ,<sup>4,5</sup>  $\text{Bi}_2\text{Te}_3$ ,<sup>6</sup>  $\text{Bi}_2\text{Se}_3$ ,<sup>7,8</sup> as well as for Pb- and TI-based ternary compounds.<sup>9-18</sup> It promises robust protection of spin-polarized surface states from backscattering in the presence of nonmagnetic impurities due to time-reversal (TR) symmetry, which is a key requirement for revolutionizing modern electronic devices. Among the discovered TI materials,  $\text{Bi}_2\text{Se}_3$  is one of the most promising candidates owing to the large bulk energy gap with a single Dirac cone surface state.

In fact, spin-selective scattering has been directly imaged by scanning tunneling microscopy (STM) even without the breaking of TR symmetry.<sup>5,19,20</sup> Especially for  $\text{Bi}_2\text{Te}_3$ , a suppressed backscattering of topological surface electrons by nonmagnetic impurities has been reported.<sup>19</sup> Note that due to the relatively small bulk energy gap and a strong anisotropy of the bulk band structure, the topological surface state of  $\text{Bi}_2\text{Te}_3$  is strongly hexagonally warped,<sup>20,21</sup> which may enhance the quasiparticle interference (QPI) with scattering vector mainly along the  $\bar{\Gamma}$ - $\bar{M}$  direction between states with out-of-plane spin components.<sup>19</sup> In other words, sufficient protection would be realized in more favorable TI materials with larger bulk energy gap, such as  $\text{Bi}_2\text{Se}_3$ .

Most interesting properties appear when the surfaces of three-dimensional (3D) TIs are interfaced with ferromagnetic layers.<sup>22-26</sup> Due to the broken TR symmetry, an energy gap opens at the Dirac point, leading to massive Dirac fermions. In such a system interesting physical phenomena will emerge, in particular the half quantum Hall

effect on the surface with a Hall conductance of  $e^2/2h$  [Ref. 27].

Experimentally, great efforts have been made to magnetically dope the bulk of TI materials. An opening of the energy gap at the Dirac point and the consequent QPI on the topological surface due to the broken TR symmetry have been directly observed.<sup>28,29</sup> On the other hand, the magnetic doping at the surface, which can be realized by the deposition of magnetic atoms, is still poorly explored though it is expected to more strongly influence the surface Dirac fermions than the bulk doping.<sup>30,31</sup> Here we show for the first time that Co atoms on the surface of  $\text{Bi}_2\text{Se}_3$  generate a distinct QPI of the surface Dirac fermions without the opening of an energy gap at the Dirac point. The absence of a long-range ferromagnetic order is revealed by combined STM, angle-resolved photoemission spectroscopy (ARPES), and x-ray magnetic circular dichroism (XMCD) experiments.

### II. EXPERIMENTAL

Our measurements were performed on the pristine  $\text{Bi}_2\text{Se}_3$  single crystal, which is naturally of  $n$  type. Clean surfaces were obtained by *in situ* cleavage in ultrahigh vacuum (UHV) at room temperature. Cobalt deposition was made at room temperature after the confirmation of the clean surface by STM. The present STM results were obtained at 4.7 K and 78 K in the constant current mode, and the differential conductance ( $dI/dV$ ) map was acquired by a standard lock-in technique. ARPES experiments were performed at BL-7 of the Hiroshima Synchrotron Radiation Center equipped with a hemispherical photoelectron analyzer (VG-SCIENIA SES2002). An XMCD experiment on a Co-deposited  $\text{Bi}_2\text{Se}_3$  surface was conducted at the twin helical undulator beam line BL23SU of SPring-8

in a total-electron yield mode, employing a superconducting magnet and a helium cryostat during the measurement.

### III. RESULTS AND DISCUSSION

#### A. Quasiparticle interference on the surface of $\text{Bi}_2\text{Se}_3$ induced by Co adatoms

Figure 1(a) shows a typical STM image acquired at a sample bias voltage of  $V_s = -300$  mV of the Co-deposited  $\text{Bi}_2\text{Se}_3$  surface. Two kinds of bright features can be identified in the image, namely the large triangular patterns and the tiny bright spots. The large features are typically found in both  $\text{Bi}_2\text{Se}_3$  and  $\text{Bi}_2\text{Te}_3$  surfaces and are assigned as the substitutional or antisite defect.<sup>32–34</sup> The tiny bright spots appear after the Co deposition and are assigned as Co adatoms. A close-up STM image of the Co adatom [marked with a white frame in Fig. 1(a)] is shown in Fig. 1(b). The 3D illustration of the Co adatom in Fig. 1(b) clearly shows the sharp protrusion on the surface with a spatial full width at half maximum of 4 Å [inset of Fig. 1(b)]. By carefully examining the atomic position in this area, we identify the Co adatom as located on the top of the Se atom, as schematically shown in Fig. 1(c).

Figure 2(a) shows a topographic STM image in a  $40 \text{ nm} \times 40 \text{ nm}$  area with 0.02 monolayer (ML) of Co deposited on a  $\text{Bi}_2\text{Se}_3$  surface. In the  $dI/dV$  images with different sample bias voltages acquired in the same area of Fig. 2(a), clear QPI features around the Co adatoms are observed. The QPI standing wave gradually changes its wave length depending on  $V_s$ ; see Figs. 2(b)–2(f). As  $V_s$  decreases, the wavelength in the real space ( $r$  space) increases. For  $V_s < 200$  mV, the interference patterns become rather diffuse. Moreover, the standing waves observed around the Co adatoms exhibit strong anisotropic shape, in contrast to what is commonly observed at high-index surfaces of pure metals.<sup>35,36</sup>

To gain a deeper insight into the relationship between the interference pattern and  $V_s$ , the real space  $dI/dV$  maps are Fourier transformed, as depicted in Fig. 3(a) for the sample bias voltage of 400 mV. The six spots marked with white dashed circles are  $(1 \times 1)$  spots in the reciprocal space, and the  $(0, 0)$  spot is located in the center of the image. The surface Brillouin zone is shown in Fig. 3(a) as a hexagon

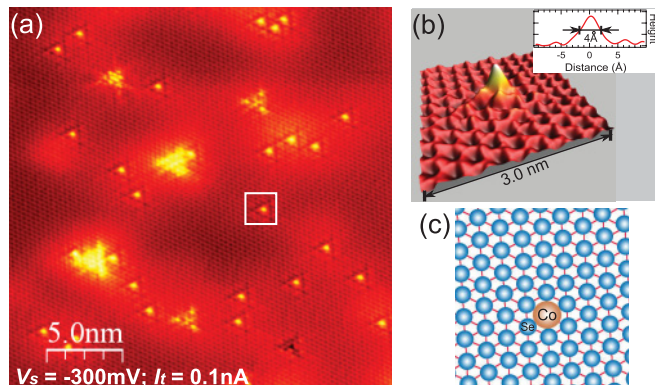


FIG. 1. (Color online) (a) STM image of Co deposited on the  $\text{Bi}_2\text{Se}_3$  surface ( $25 \text{ nm} \times 25 \text{ nm}$ ). (b) 3D illustration of a Co adatom in the square in panel (a). The inset shows a cross-sectional profile of the Co adatom on  $\text{Bi}_2\text{Se}_3$ . (c) Schematic of atomic structure in panel (b).

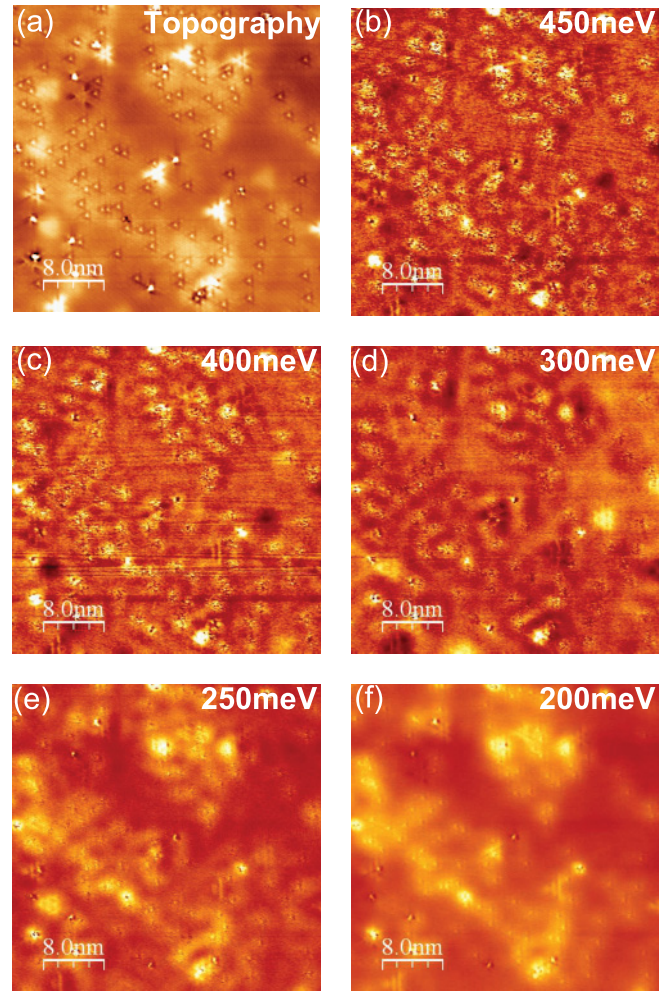


FIG. 2. (Color online) (a) A  $40 \text{ nm} \times 40 \text{ nm}$  area STM image of Co (0.02 ML) evaporated  $\text{Bi}_2\text{Se}_3$  surface (sample bias 300 mV, set point 0.10 nA, 4.5 K); (b)–(f)  $dI/dV$  images taken at the same area as (a) with different sample bias voltages (set point 0.10 nA, 4.5 K).

with the  $\bar{\Gamma}$  point located in the center. The reciprocal space image in Fig. 3(a) reveals the anisotropic interference patterns with sixfold symmetry. The intensity maximum is in the  $\bar{\Gamma}$ - $\bar{M}$  direction as shown by the cross-sectional profiles at different sample bias voltages in Fig. 3(b). The sixfold pattern gradually shrinks with decreasing  $V_s$ , and eventually vanishes below 200 mV, as indicated by arrows in Fig. 3(b). Further quantitative analysis reveals that wave number of the peak in the cross-sectional profiles along  $\bar{\Gamma}$ - $\bar{M}$  almost linearly shifts with  $V_s$  [Fig. 3(c)].

When the TR symmetry is broken due to the ferromagnetism with perpendicular magnetic anisotropy with respect to the TI surface, the energy gap formed at the Dirac point would simultaneously result in the opening of the scattering channels at all energies. Thus, the vanishing of the standing waves below 200 mV in the  $dI/dV$  map suggests that the TR protection of the topological surface state persists without a gap opening at the Dirac point even in the presence of Co impurities. The scattering observed with large sample bias voltages in the unoccupied states can be ascribed to a heavily deformed iso-energy contour in the high energy range (the



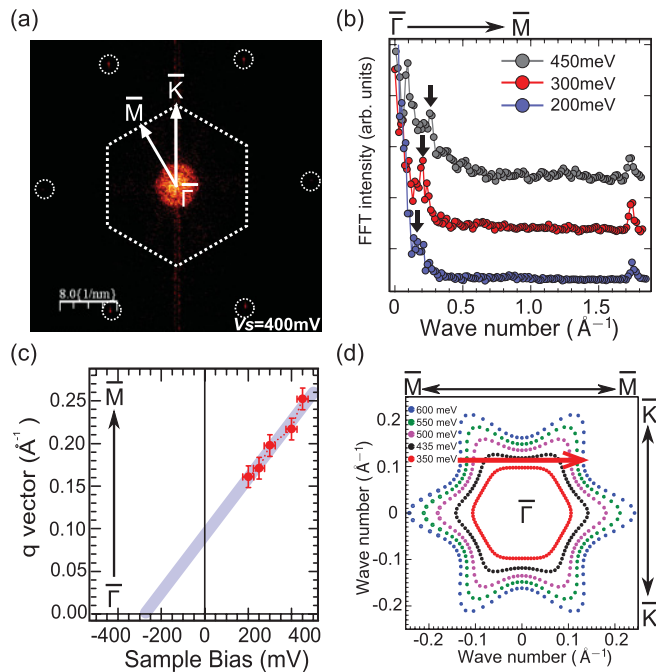


FIG. 3. (Color online) (a) Fourier-transformed  $dI/dV$  images acquired at  $V_S = 400 \text{ mV}$ ; the surface Brillouin zone is indicated by the white dashed hexagon. (b) Profile curves of Fourier-transformed image along  $\bar{\Gamma}$ - $\bar{M}$  at different sample bias voltages. (c) Plot of the interference peak along the  $\bar{\Gamma}$ - $\bar{M}$  direction [indicated by an arrow in panel (c)] as a function of sample bias voltages. (d) Calculated constant energy contour relative to the Dirac point of  $\text{Bi}_2\text{Se}_3$ ; the red arrow indicates the scattering channel along  $\bar{\Gamma}$ - $\bar{K}$  due to the perpendicular spin component.

unoccupied states) as indicated by the scattering vector superimposed on the calculated constant energy contours in Fig. 3(d). The scattering channel is allowed because of the finite spin component in the direction perpendicular to the surface.<sup>8,37,38</sup> When the sample bias voltage goes below 200 mV, where the hexagonal warping effect in  $\text{Bi}_2\text{Se}_3$  is negligible, a fast Fourier transformation (FFT) image of the  $dI/dV$  map exhibits only a blurred intensity in the center without specific singularities, as has been theoretically predicted.<sup>39</sup>

### B. Robustly protected topological states against Co doping

To see how the surface state dispersion is modified upon Co deposition, we have employed ARPES with synchrotron radiation. Here, we use the photon energy of 50 eV, at which the spectral weight of the bulk conduction band is largely suppressed and the surface Dirac cone is highlighted.

As shown in Fig. 4(a), the linear surface state dispersion is clearly observed before as well as after the Co deposition, but the background is stronger with larger Co coverage. The Dirac point prior to the Co deposition is located at 340 meV below the Fermi level. After 0.2-ML Co deposition, the Dirac point shifts to 390 meV, and no other significant changes of the Dirac cone are observed. When the amount of Co increases to 0.9 ML, a larger energy shift of  $\sim 100 \text{ meV}$  is observed with stronger background intensity. However, neither the change of spectral feature nor the energy gap opening is observed. These results

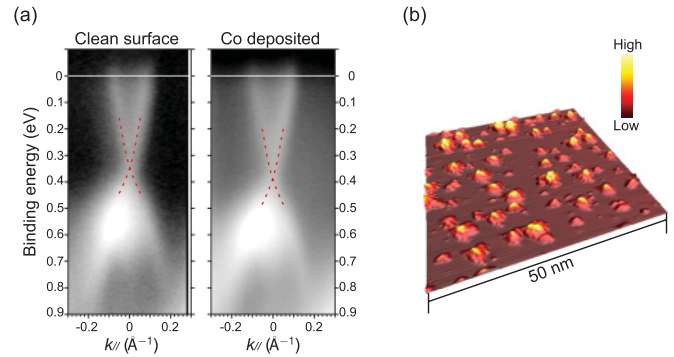


FIG. 4. (Color online) (a) ARPES measurement before and after 0.2-ML Co deposited on  $\text{Bi}_2\text{Se}_3$  acquired by photon energy of 50 eV. (b) STM image of 0.2-ML Co deposited on  $\text{Bi}_2\text{Se}_3$  ( $V_S = -2.0 \text{ V}$ ,  $I_t = 0.15 \text{ nA}$ , 78 K).

imply either the absence of the ferromagnetic order or the vanishing of the magnetic moment of Co atoms deposited on the surface of  $\text{Bi}_2\text{Se}_3$ , which may be ascribed to the chemical bonding with Se atoms on the topmost layer. The increasing of spectral background after Co deposition can be explained as the formation of random Co cluster on the  $\text{Bi}_2\text{Se}_3$  surface, as shown by the STM image in Fig. 4(b). Thus, the QPI observed in the present STM results are interpreted as originating from the deformation of the Fermi surface<sup>8,37</sup> rather than from a broken TR symmetry.

### C. Element-specific magnetic properties of Co deposited on $\text{Bi}_2\text{Se}_3$ surface

Finally, to understand the magnetic properties of Co on the surface of  $\text{Bi}_2\text{Se}_3$ , we have performed x-ray magnetic circular dichroism measurement, which is able to resolve element-specific magnetic properties. Figure 5(a) shows the Co  $L_{23}$  x-ray absorption spectra (XAS) for three different coverages. Also the absorption spectrum of the clean sample is measured to estimate the background contribution. As can be seen in Fig. 5(a), when the coverage of Co increases from 0.02 to 0.45 ML, the total absorption intensities at 778 and 793 eV gradually increase. The XMCD spectrum is obtained by measuring the difference of the absorption intensities with the circular polarization vector of the incident light parallel and antiparallel to the magnetic field. Figure 5(b) shows the XMCD spectra acquired under an 8-T magnetic field applied perpendicular to the sample surface at 5 K. The intensity of the XMCD signal of both  $L_3$  and  $L_2$  edges increases with increasing Co coverage. Note that the ratio between the orbital and spin magnetic moment deduced from the XMCD spectra of the Co layer deposited on  $\text{Bi}_2\text{Se}_3$  ( $m_{\text{orb}}/m_{\text{spin}} \sim 0.3\text{--}0.5$ ) for the three measured Co coverages is considerably larger than for that of bulk Co crystal ( $m_{\text{orb}}/m_{\text{spin}} \sim 0.1$ ) [Ref. 40].

Whether the Co-deposited  $\text{Bi}_2\text{Se}_3$  surfaces are ferromagnetic or not can be inferred by investigating site-specific magnetization as a function of magnetic field. Figure 5(c) shows the intensity of the XMCD signal at Co  $L_3$  edges as a function of the magnetic field ( $M$ - $H$  curve), which is swept from  $-8$  to  $8 \text{ T}$  and then back to  $-8 \text{ T}$  to form a loop. As is seen from Fig. 5(c), the  $M$ - $H$  curves for all the three coverages of Co increase in the same direction with increasing magnetic field strength. However, the intensity of

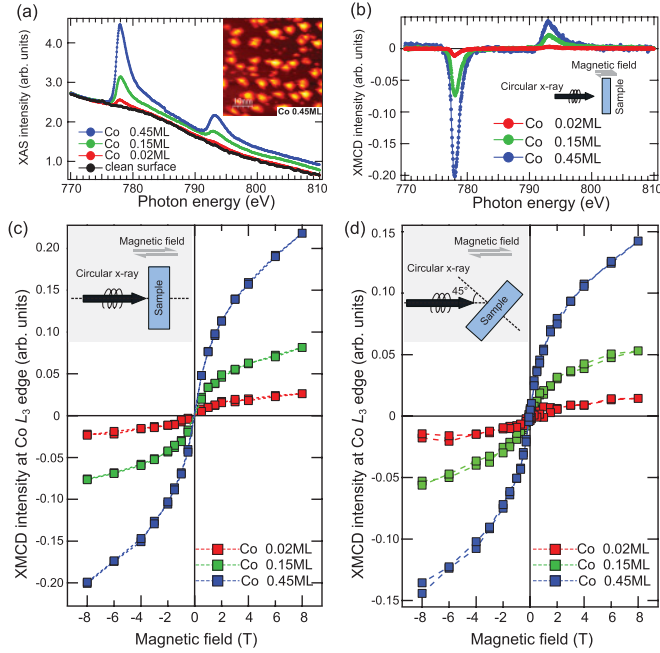


FIG. 5. (Color online) (a) XAS spectra at Co  $L_{23}$  absorption edges with different Co coverages of 0.02 ML, 0.15 ML, and 0.45 ML. The inset shows a STM image of a 0.45-ML Co on a  $\text{Bi}_2\text{Se}_3$  surface ( $50 \text{ nm} \times 50 \text{ nm}$ ,  $V_s = -2.0 \text{ V}$ ,  $I_t = 0.15 \text{ nA}$ , 78K). (b) XMCD spectra at Co  $L_{23}$  edges acquired at 5 K, when the magnetic field is applied perpendicular to sample surface. Site-specific magnetization measurement of Co  $L_3$  edges with different coverages of Co on  $\text{Bi}_2\text{Se}_3$  surface are shown when the magnetic field is (c) perpendicular and (d)  $45^\circ$  tilted to the sample surface (temperature, 5 K).

the  $M$ - $H$  curves is not saturated even at 8 T, and no magnetic hysteresis is observed for any of the three Co coverages. These results clearly show that the Co layer on the  $\text{Bi}_2\text{Se}_3$  surface has no long-range ferromagnetic order. This is consistent with our ARPES results, which show no gap opening at the Dirac point upon Co deposition, and thereby confirm that the QPI patterns observed in the STM experiment originate from the strongly warped Dirac cone in the unoccupied states of  $\text{Bi}_2\text{Se}_3$ . Moreover, in order to investigate the magnetization parallel to the  $\text{Bi}_2\text{Se}_3$  surface, we further measured the Co-deposited surface with a tilt angle ( $45^\circ$ ) from the incident x ray and the magnetic field [Fig. 5(d)]. Similar to the case of perpendicular magnetization, the absence of long-range magnetic order has also been confirmed for the in-plane component of magnetization.

In order to further investigate the magnetic state of cobalt on the surface, we have performed *ab initio* DFT calculations using the VASP code.<sup>41–43</sup> We considered a single Co adatom within a slab model of a  $3 \times 3$  surface supercell of  $\text{Bi}_2\text{Se}_3$ . The lateral position of the atom was fixed to be above the Se atom in accordance with our STM data, and the height of the Co atom above the top Se atom was optimized to be 2.27 Å (within a collinear scalar-relativistic approximation). The magnetic properties of the Co adatom in this position were calculated with the inclusion of the spin-orbit coupling. The magnetic moment of the Co adatom is found to be  $2.06 \mu_B$  along the  $z$  axis. At the same time, the magnetic adatom does not induce a noticeable spin polarization of the substrate. The

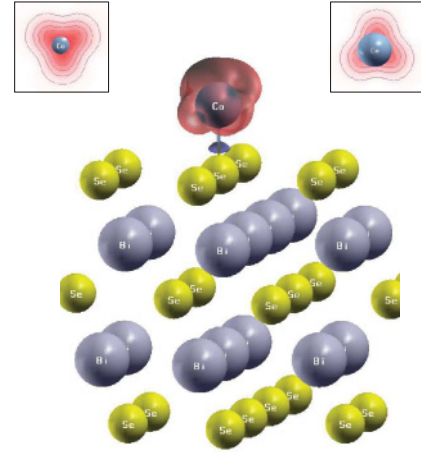


FIG. 6. (Color online) Constant-density surface for perpendicular ( $z$ ) magnetization density (red and blue colors correspond to positive and negative values, respectively). Insets show cross-sections of this surface in  $xy$  plane just above (left) and below (right) the Co atom center.

calculated  $z$ -magnetization density is shown in Fig. 6. The obtained negligible polarization of the substrate explains why the magnetic interaction between the adsorbed Co atoms is extremely weak and why no ferromagnetic ordering at a low Co coverage is observed in the experiment.

#### IV. CONCLUSION

In summary, by measuring the bias-dependent differential conductance mapping, we have observed the QPI of Dirac electrons induced by Co impurities. The magnetic properties of Co-deposited  $\text{Bi}_2\text{Se}_3$  surfaces investigated by XMCD reveal an absence of ferromagnetism, in agreement with our ARPES results that the gapless topological surface state is not destroyed by the Co impurities. We conclude that the QPI near Co impurities originates from the strongly deformed isoenery contours of the unoccupied states of  $\text{Bi}_2\text{Se}_3$ . These results provide a pathway to further understanding on the topological nontrivial states in the presence of magnetic impurities.

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